Features

- Halogen Free. 鈥溾榬reen鈥?Device (Note 1)
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

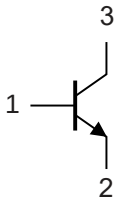
Maximum Ratings @ 25°C Unless Otherwise Specified

- Operating Junction Temperature Range: -55℃ to +150℃
- Storage Temperature Range: -55℃ to +150℃
- Thermal Resistance: 417℃/W Junction to Ambient

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	25	V
Emitter-Base Voltage	V_{EBO}	5	V
Continuous Collector Current	I_C	500	mA
Power Dissipation	P_D	300	mW

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

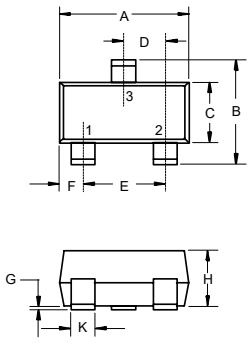
Internal Structure



1.BASE
2.EMITTER
3.COLLECTOR

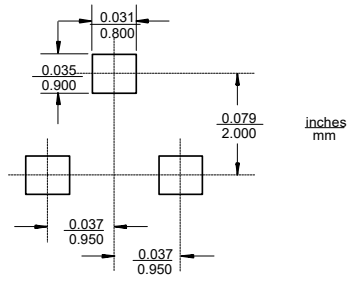
NPN Silicon General Purpose Transistors

SOT-23



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.110	0.120	2.80	3.04	
B	0.083	0.104	2.10	2.64	
C	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
E	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.006	0.01	0.15	
H	0.035	0.043	0.90	1.10	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

Suggested Solder Pad Layout



Electrical Characteristics @ T_A=25°C Unless Otherwise Specified

Parameter	Symbol	Min	Typ	Max	Units	Conditions
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	30			V	I_C=10μA, I_E=0
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	25			V	I_C=10mA, I_B=0
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5			V	I_E=10μA, I_C=0
Collector-Base Cutoff Current	I_{CBO}			0.1	μA	V_{CB}=25V, I_E=0
Emitter-Base Cutoff Current	I_{EBO}			0.1	μA	V_{EB}=4V, I_C=0
DC Current Gain	$h_{FE(1)}$	100		630		V_{CE}=1V, I_C=100mA
	$h_{FE(2)}$	60				V_{CE}=1V, I_C=300mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			0.7	V	I_C=500mA, I_B=50mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$			1.2	V	I_C=500mA, I_B=50mA
Base-Emitter Voltage	V_{BE}			1.2	V	V_{CE}=1V, I_C=500mA
Transition Frequency	f_T		170		MHz	V_{CE}=5V,I_C=50mA,f=100MHz
Collector Output Capacitance	C_{ob}		6		pF	V_{CB}=10V,I_E=0,f=1MHz

Classification of $h_{FE(1)}$

Rank	16	25	40
Range	100-250	160-400	250-630
Marking	6E	6F	6G

Curve Characteristics

Fig. 1 - Static Characteristics

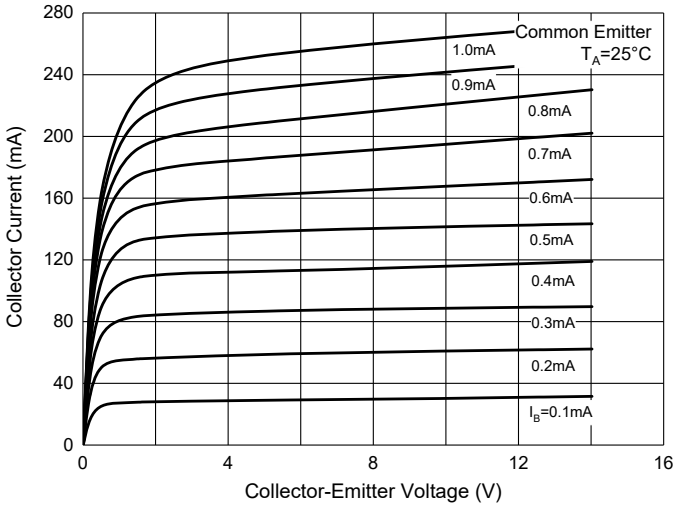


Fig. 2 - DC Current Gain Characteristics

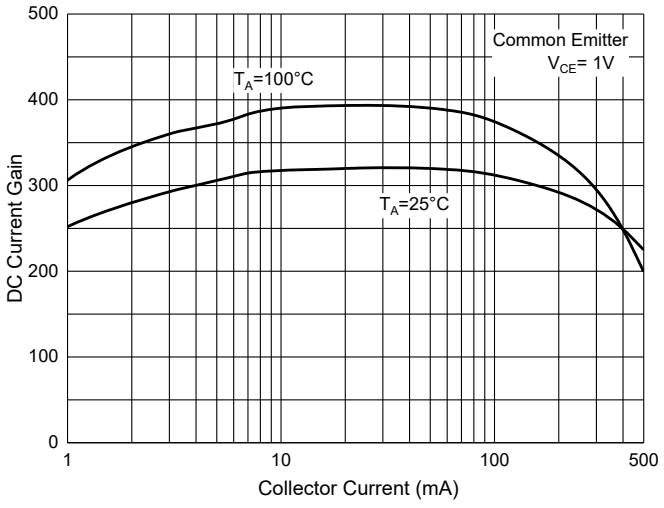


Fig. 3 - Base-Emitter Saturation Voltage Characteristics

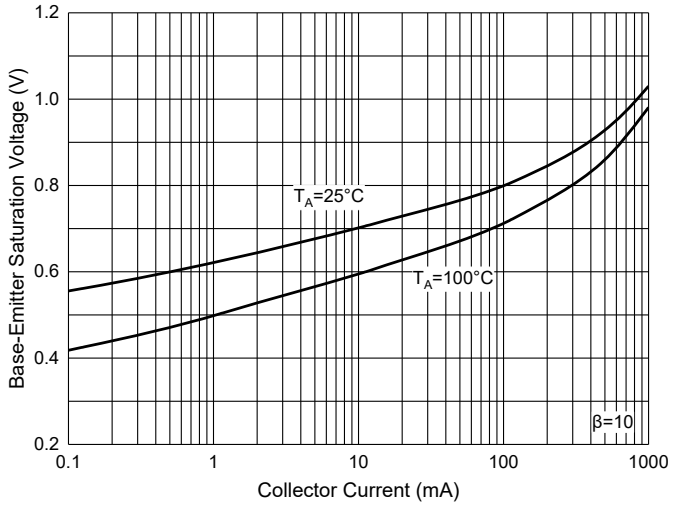


Fig. 4 - Collector-Emitter Saturation Voltage Characteristics

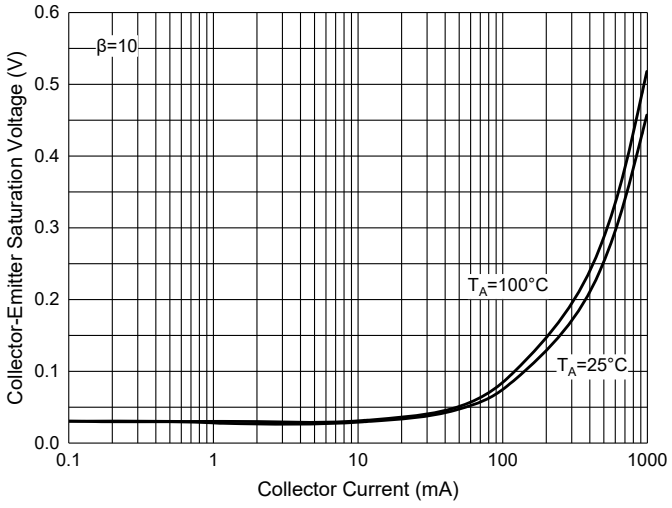


Fig. 5 - Base-Emitter Voltage Characteristics

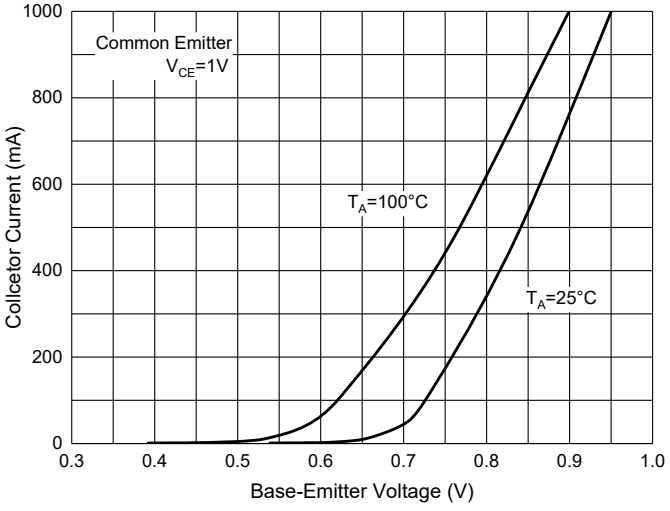
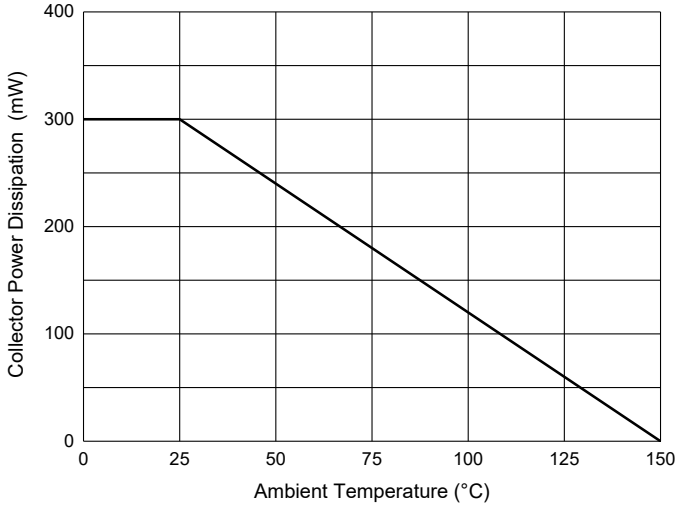


Fig. 6 - Collector Power Derating Curve



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel